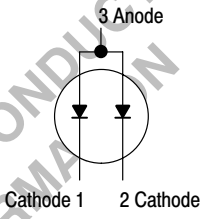
MSD6150

Dual Diode
Common Anode

ON Semiconductor®

http://onsemi.com

TO−92
(TO−226AA)
CASE 29−11
STYLE 4



MAXIMUM RATINGS (EACH DIODE)

Rating	Symbol	Value	Unit
Reverse Voltage	V_R	70	Vdc
Peak Forward Recurrent Current	I_F	200	mAdc
Peak Forward Surge Current (Pulse Width = 10 μsec)	$I_{FM(surge)}$	500	mAdc
Total Device Dissipation @ T_A = 25°C Derate above 25°C	P_D(1)	625 5.0	mW mW/°C
Operating and Storage Junction Temperature Range	T_J, T_{stg}(1)	−55 to +135	°C

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted) **(EACH DIODE)**

Characteristic	Symbol	Min	Typ	Max	Unit
Breakdown Voltage ($I_{(BR)}$ = 100 μAdc)	$V_{(BR)}$	70	—	—	Vdc
Reverse Current (V_R = 50 Vdc)	I_R	—	—	0.1	μAdc
Forward Voltage (I_F = 10 mAdc)	V_F	—	0.80	1.0	Vdc
Capacitance (V_R = 0)	C	—	5.0	8.0	pF
Reverse Recovery Time (I_F = I_R = 10 mAdc, V_R = 5.0 Vdc, i_{rr} = 1.0 mAdc)	t_{rr}	—	—	100	ns

1. Continuous package improvements have enhanced these guaranteed Maximum Ratings as follows: P_D = 1.0 W @ T_C = 25°C, Derate above 8.0 mW/°C, P_D = 10 W @ T_C = 25°C, Derate above 80 mW/°C, T_J, T_{stg} = −55 to +150°C, θJC = 12.5°C/W, θJA = 125°C.

TYPICAL CHARACTERISTICS

Curves Applicable to Each Cathode

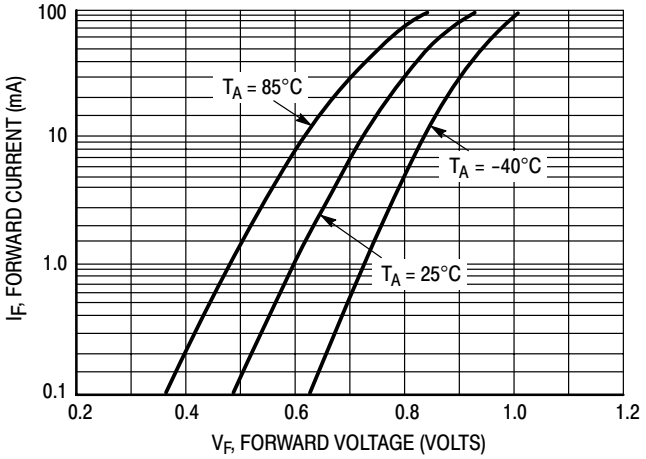


Figure 1. Forward Voltage

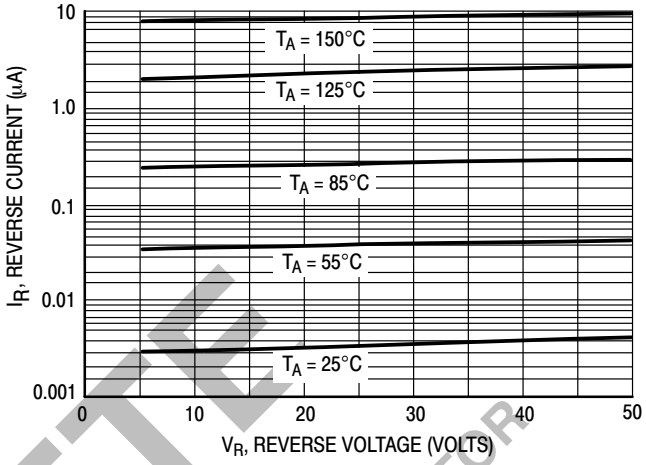


Figure 2. Leakage Current

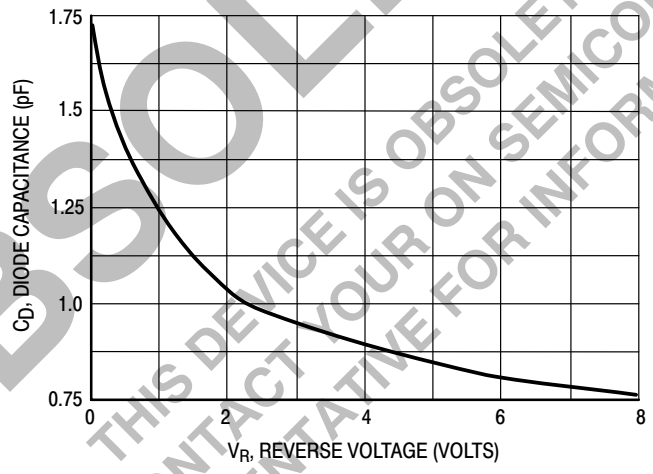


Figure 3. Capacitance

PACKAGE DIMENSIONS

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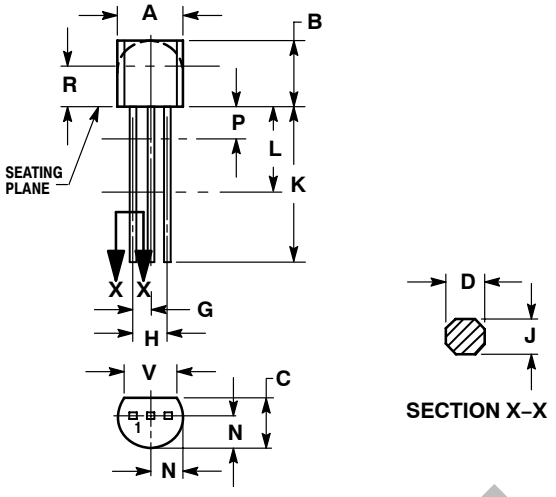
ISSUE AL



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	---	12.70	---
L	0.250	---	6.35	---
N	0.080	0.105	2.04	2.66
P	---	0.100	---	2.54
R	0.115	---	2.93	---
V	0.135	---	3.43	---

STYLE 4:
PIN 1. CATHODE
2. CATHODE
3. ANODE

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